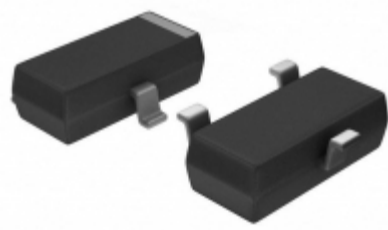


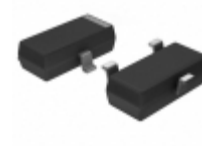
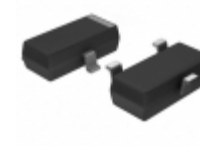




	<h2 style="color: red;">FJV3110RMTF</h2>
	<p>Hersteller-Teilenummer: FJV3110RMTF</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: TRANS PREBIAS NPN 200MW SOT23-3</p> <p>Datenblätter: 1.FJV3110RMTF.pdf 2.FJV3110RMTF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 30980 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FJV3110RMTF
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	TRANS PREBIAS NPN 200MW SOT23-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-Bipolar
Teilstatus	30980 pcs Stock
Hersteller Standard Vorlaufzeit	13 Weeks
detaillierte Beschreibung	Pre-Biased Bipolar Transistor (BJT) NPN - Pre-Biased
Serie	-
Befestigungsart	Surface Mount
Leistung - max	200mW
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Transistor-Typ	NPN - Pre-Biased
Strom - Kollektor (Ic) (max)	100mA
Spannung - Kollektor-Emitter-Durchbruch (max)	40V
VCE Sättigung (Max) @ Ib, Ic	300mV @ 1mA, 10mA
Strom - Collector Cutoff (Max)	100nA (ICBO)
DC Stromgewinn (HFE) (Min) @ Ic, VCE	100 @ 1mA, 5V
Frequenz - Übergang	250MHz
Verpackung	Tape & Reel (TR)
Basisteilenummer	FJV3110
Widerstand - Basis (R1)	10 kOhms
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FJV3110RMTF-ND

FJV3110RMTF ist neu im Original, Suche FJV3110RMTF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FJV3110RMTF AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FJV3110RMTF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FJV3111RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3111RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3109RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>
 <p>FJV3112RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3108RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3112RMTF AMI Semiconductor / ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>	 <p>FJV3110RMTF Fairchild/ON Semiconductor TRANS PREBIAS NPN 200MW SOT23-3</p>

heiße Teile

Mehr

⚙ FJV1845FMTF	↔ FJV1845PMTF	⇒ FJV1845PMTF	D FJV1845UMTF	⇒ FJV1845UMTF
⊣ FJV3101RLIMTF	⚙ FJV3101RMTF	D FJV3101RMTF	⇒ FJV3102RMTF	⇒ FJV3102RMTF
⚙ FJV3103RMTF	⊣ FJV3103RMTF	⚙ FJV3104RMTF	↔ FJV3104RMTF	⇒ FJV3105RMTF
D FJV3105RMTF	⚙ FJV3106RMTF	⊣ FJV3106RMTF	⚙ FJV3107RMTF	⇒ FJV3107RMTF
⇒ FJV3108RMTF	↔ FJV3108RMTF	⚙ FJV3109R	⊣ FJV3109RMTF	⇒ FJV3109RMTF
↔ FJV3110RMTF	⇒ FJV3111RMTF	D FJV3111RMTF	⚙ FJV3112RMTF	⊣ FJV3112RMTF
⚙ FJV3113RMTF	D FJV3113RMTF	⇒ FJV3114RMTF	↔ FJV3114RMTF	⇒ FJV3115RMTF
⊣ FJV3115RMTF	⚙ FJV4101RMTF	↔ FJV4101RMTF	⇒ FJV4102RLIMTF	⇒ FJV4102RMTF
⚙ FJV4102RMTF	⊣ FJV4103RMTF	⚙ FJV4103RMTF	D FJV4104RMTF	⇒ FJV4104RMTF
↔ FJV4105RMTF	⚙ FJV4105RMTF	⊣ FJV4106RMTF	⚙ FJV4106RMTF	⇒ FJV4107RMTF

Contact us: Info@Y-IC.com

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